# NSN 5962-01-293-7702

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## Body Length:

1.490 inches

#### **Body Width:**

Between 0.500 inches and 0.610 inches

#### **Body Height:**

0.210 inches

#### **Maximum Power Dissipation Rating:**

1.0 watts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **Features Provided:**

Monolithic and hermetically sealed and asynchronous and w/enable

#### Inclosure Material:

Ceramic

#### Inclosure Configuration:

Dual-in-line

#### **Output Logic Form:**

Complementary-metal oxide-semiconductor logic

#### Input Circuit Pattern:

21 input

#### Case Outline Source And Designator:

D-10 mil-m-38510

#### **Terminal Surface Treatment:**

Solder

#### Voltage Rating And Type Per Characteristic:

7.0 volts power source

#### **Time Rating Per Chacteristic:**

150.00 nanoseconds propagation delay time, low to high level output and 150.00 nanoseconds propagation delay time, high to low level output

#### Memory Device Type:

Ram

### Test Data Document:

81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

## Terminal Type And Quantity:

28 printed circuit

### **Specification Data:**

81349-mil-m-38510/292 government specification

## Shelf Life:

N/a

## Unit Of Measure:

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## Demilitarization:

Yes - demil/mli

Fiig:

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